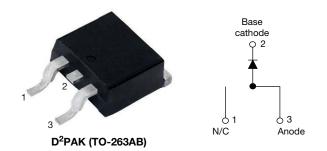
Vishay Semiconductors

High Performance Schottky Rectifier, 15 A



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PRIMARY CHARACTERISTICS							
I _{F(AV)} 15 A							
V _R	60 V						
V _F at I _F	0.56 V						
I _{RM} typ.	45 mA at 125 °C						
T _J max.	150 °C						
E _{AS}	6 mJ						
Package	D ² PAK (TO-263AB)						
Circuit configuration	Single						

FEATURES

- 150 °C T_J operation
- Very low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-15TQ060S-M3 Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL CHARACTERISTICS VALUES									
I _{F(AV)}	Rectangular waveform	15	А						
V _{RRM}		60	V						
I _{FSM}	t _p = 5 μs sine	1000	А						
V _F	15 A _{pk} , T _J = 125 °C	0.56	V						
TJ	Range	-55 to +150	°C						

VOLTAGE RATINGS							
PARAMETER SYMBOL VS-15TQ060S-M3 UNITS							
Maximum DC reverse voltage	V _R	60	V				
Maximum working peak reverse voltage	V _{RWM}	- 60 V					

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS				
Maximum average forward current, see fig. 5	I _{F(AV)}	50 % duty cycle at $T_C = 104$ °C	15	А					
Maximum peak one cycle non-repetitive surge current, see fig. 7	I _{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated	1000	А				
		10 ms sine or 6 ms rect. pulse	load condition and with rated V _{RRM} applied	260					
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 1.5 \text{ A}, L = 11.8$	6	mJ					
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T _J maxim	1.50	А					

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST C	TEST CONDITIONS					
Maximum forward voltage drop See fig. 1		15 A	T.I = 25 °C	0.62				
	V (1)	30 A	1j=25 C	0.82	V			
	V _{FM} ⁽¹⁾	15 A	T _{.1} = 125 °C	0.56				
		30 A	1j = 125 C	0.71				
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	0.80	mA			
Maximum reverse leakage current		T _J = 125 °C	V _R = naleu V _R	160	ША			
Typical reverse leakage current	I _{RM} ⁽¹⁾	T _J = 125 °C	V _R = Rated V _R	45	mA			
Maximum junction capacitance	Im junction capacitance C_T $V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz),		ange 100 kHz to 1 MHz), 25 °C	720	pF			
Typical series inductance	L _S	Measured lead to lead 5	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

Note

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 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to 150	°C		
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	3.25	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.50	0/11		
Approximate weight	A second transfer in the late			2	g		
Approximate weight				0.07	oz.		
Mounting torque	minimum			6 (5)	kgf · cm		
Mounting torque	maximum			12 (10)	(lbf · in)		
Marking device			Case style D ² PAK (TO-263AB)	15TQ	060S		

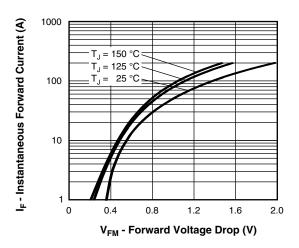


Fig. 1 - Maximum Forward Voltage Drop Characteristics

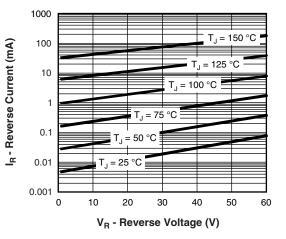


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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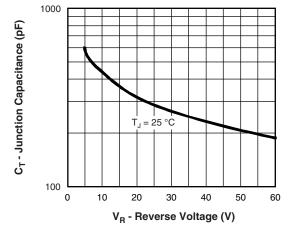


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

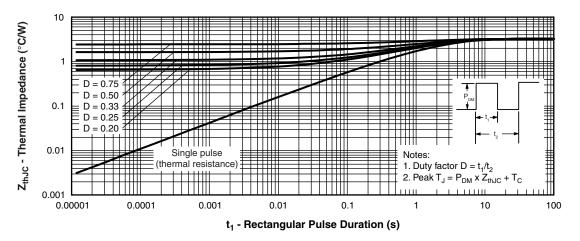
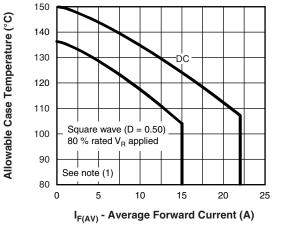
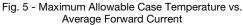


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Average Power Loss (W)





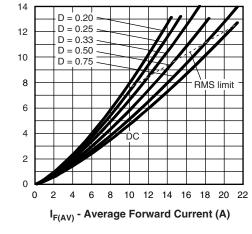


Fig. 6 - Forward Power Loss Characteristics

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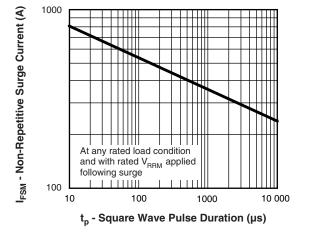


Fig. 7 - Maximum Non-Repetitive Surge Current

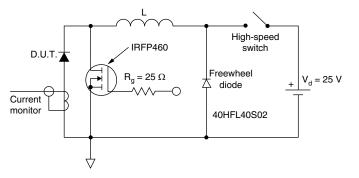


Fig. 8 - Unclamped Inductive Test Circuit

Note

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 $\begin{array}{l} \mbox{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \mbox{forward power loss} = I_{F(AV)} \times V_{FM} \mbox{ at } (I_{F(AV)}/D) \mbox{ (see fig. 6);} \\ Pd_{REV} = \mbox{inverse power loss} = V_{R1} \times I_R \mbox{ (1 - D); } I_R \mbox{ at } V_{R1} = 80 \ \% \mbox{ rated } V_R \end{array}$

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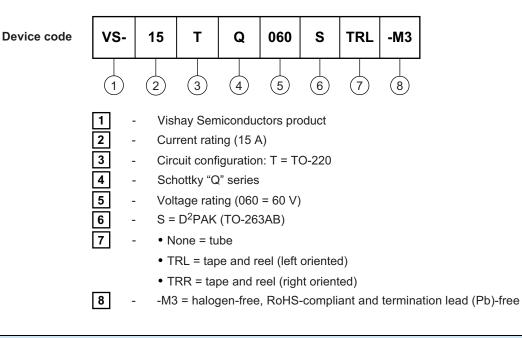
⁽¹⁾

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ORDERING INFORMATION TABLE

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ORDERING INFORMATION								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-15TQ060S-M3	50	Antistatic plastic tubes						
VS-15TQ060STRL-M3	800	13" diameter plastic tape and reel						
VS-15TQ060STRR-M3	800	13" diameter plastic tape and reel						

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?96164					
Part marking information	www.vishay.com/doc?95444					
Packaging information	www.vishay.com/doc?96424					
SPICE model	www.vishay.com/doc?95600					

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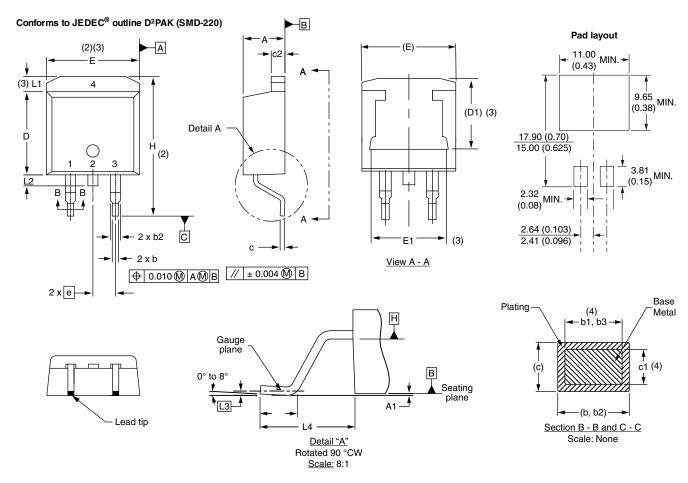


Outline Dimensions

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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	MILLIMETERS		INCHES	NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	IOTES	STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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